

The SG - 103 reflective sensor for paper sensing combine high - output GaAs IRED with high sensitivity phototransistor. It is most applicable to paper sensor.

### FEATURES

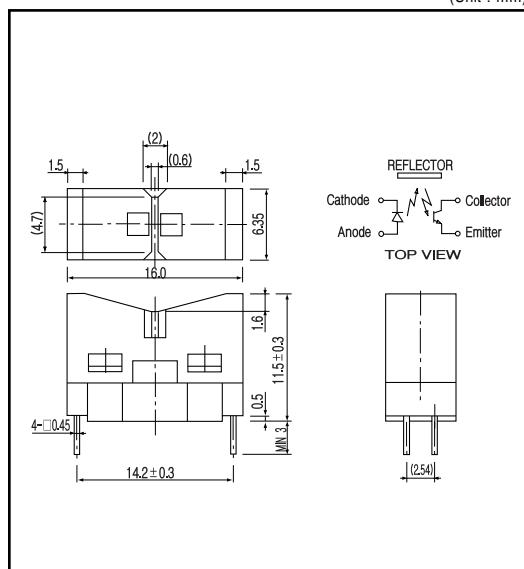
- High performance
- High - speed response
- Dust proof

### APPLICATIONS

- Copiers
- Facsimiles
- Edge sensors

### DIMENSIONS

(Unit : mm)



### MAXIMUM RATINGS

(Ta=25 °C)

Item	Symbol	Rating	Unit
Input	P <sub>D</sub>	100	mW
	V <sub>R</sub>	5	V
	I <sub>F</sub>	60	mA
	I <sub>FP</sub>	1	A
Output	P <sub>C</sub>	100	mW
	I <sub>C</sub>	40	mA
	V <sub>CEO</sub>	30	V
	V <sub>ECD</sub>	5	V
Operating temp.	Topr.	- 20 ~ + 85	
Storage temp.	Tstg	- 30 ~ + 85	
Soldering temp. <sup>2</sup>	Tsol.	240	

\*1. t w 100 μsec.period : T=10msec.

\*2. For MAX. 5 seconds at the position of 2mm from the package

### ELECTRO-OPTICAL CHARACTERISTICS

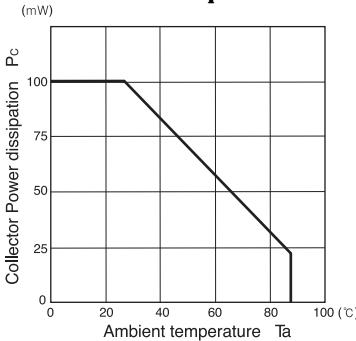
(Ta=25 °C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Input	V <sub>F</sub>	I <sub>F</sub> =30mA		1.2	1.5	V
	I <sub>R</sub>	V <sub>R</sub> =5V			10	μA
	C <sub>t</sub>	V=0V, f=1KHz		25		pF
	λ			940		nm
Output	I <sub>CEO</sub>	V <sub>CEO</sub> =10V			0.1	μA
Ligh current	I <sub>L</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =20mA	100			μA
Leakage current	I <sub>CEO</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =20mA			10	μA
Switching speeds	Rise time	tr	V <sub>CC</sub> =5V, I <sub>C</sub> =100μA	30		μsec.
	Fall time	t <sub>f</sub>	R <sub>L</sub> =1K	30		μsec.

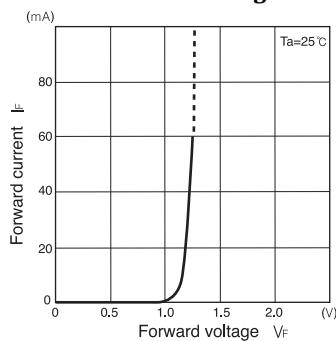
## Photointerrupters(Reflective)

SG - 103

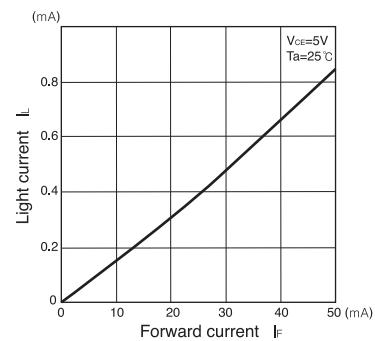
**Collector power dissipation Vs.  
Ambient temperature**



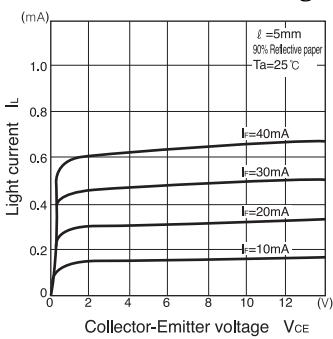
**Forward current Vs.  
Forward voltage**



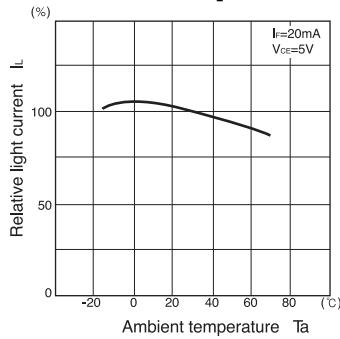
**Light current Vs.  
Forward current**



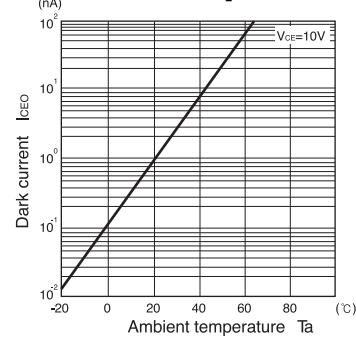
**Light current Vs.  
Collector-Emitter voltage**



**Relative light current Vs.  
Ambient temperature**



**Dark current Vs.  
Ambient temperature**



**Switching time Vs.  
Load resistance**

